

Product / Process Change Notification



N° 2018-037-A

Dear Customer,

Please find attached our INFINEON Technologies PCN:

Introduction of Additional Wafer Production Site with 8" Wafer Diameter for 1200V Emitter Controlled HE Diodes

Important information for your attention:

- Please respond to this PCN by indicating your decision on the approval form, sign it and return to your sales partner before **29th May 2018**.
- Infineon aligns with the widely-recognized JEDEC STANDARD "**JESD46**", which stipulates:
"Lack of acknowledgement of the PCN within 30 days constitutes acceptance of the change."

Your prompt reply will help Infineon Technologies to assure a smooth and well executed transition. If Infineon does not hear from your side by the due date, we will assume your full acceptance to this proposed change and its implementation.

Your attention and response to this matter is greatly appreciated.

Infineon Technologies AG
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Chairman of the Supervisory Board: Dr. Eckart Süner
Management Board: Dr. Reinhard Ploss (CEO), Dominik Asam, Dr. Helmut Gassel, Jochen Hanebeck
Registered Office: Neubiberg Commercial Register
Amtsgericht München HRB 126492

Product / Process Change Notification



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► **Products affected:**

Please refer to attached affected product list
“pcn_2018-037-A_[customer-no].pdf”

► **Detailed Change Information:**

Subject: Introduction of additional wafer production site with 8” Wafer diameter for 1200V Emitter Controlled HE diodes

Reason: Capacity extension and increasing security of supply 1200V Diode
For Diodes the 8” wafer manufacturing technology is, State of the Art’ wafer manufacturing technology at Infineon.

Description:

<u>Old</u>	<u>New</u>
<ul style="list-style-type: none">1200V Emitter Controlled HE Diode <p>8” inch: - Front end Villach/ Austria</p>	<ul style="list-style-type: none">1200V Emitter Controlled HE Diode <p>8” inch: - Front end Villach/ Austria - Front end Kulim/ Malaysia</p> <p>-> Target production site Kulim/ Malaysia 8” inch</p>

► **Product Identification:**

Individual production lot number

► **Impact of Change:**

No impact on electrical performance. Quality and reliability verified by qualification. There is no change in form, fit and function There is no change in the assembly process at Infineon.

► **Attachments:**

Affected product list “pcn_2018-037-A_[customer-no].pdf”

► **Time Schedule:**

- Final qualification report: available
- First samples available: on request
- Intended start of delivery: 2018-05-01 depending on customer approval

If you have any questions, please do not hesitate to contact your local Sales office.

PCN 2018-037-A

Introduction of Additional Wafer Production Site with 8" Wafer Diameter for 1200V Emitter
Controlled HE Diodes

Affected products sold to FUTURE ELECTRONICS INC. (4000624)

Sales name	SP number	OPN	Package	Customer part number
DF900R12IP4D	SP000721126	DF900R12IP4DBOSA1	AG-PRIME2-1-1	DF900R12IP4DBOSA1
F3L400R12PT4_B26	SP000929974	F3L400R12PT4B26BOSA1	AG-ECONO4-1-1	F3L400R12PT4B26BOSA1
FF200R12KT4	SP000370618	FF200R12KT4HOSA1	AG-62MM-1-1	FF200R12KT4HOSA1
FF225R12ME4	SP000405064	FF225R12ME4BOSA1	AG-ECONOD-3-1	FF225R12ME4BOSA1
FF300R12KT4	SP000370607	FF300R12KT4HOSA1	AG-62MM-1-1	FF300R12KT4HOSA1
FF300R12ME4	SP000405060	FF300R12ME4BOSA1	AG-ECONOD-3-1	FF300R12ME4BOSA1
FF450R12KT4	SP000370613	FF450R12KT4HOSA1	AG-62MM-1-1	FF450R12KT4HOSA1
FF450R12ME3	SP000317626	FF450R12ME3BOSA1	AG-ECONOD-3-1	FF450R12ME3BOSA1
FF450R12ME4	SP000389732	FF450R12ME4BOSA1	AG-ECONOD-3-1	FF450R12ME4BOSA1
FF600R12ME4	SP000635448	FF600R12ME4BOSA1	AG-ECONOD-5-1	FF600R12ME4BOSA1
FS150R12KE3G	SP000100403	FS150R12KE3GBOSA1	AG-ECONOPP-1-1	FS150R12KE3GBOSA1
FS200R12KT4R	SP000715004	FS200R12KT4RBOSA1	AG-ECONO3-4-1	FS200R12KT4RBOSA1
FS225R12KE3	SP000100404	FS225R12KE3BOSA1	AG-ECONOPP-1-1	FS225R12KE3BOSA1
FS300R12KE3	SP000100405	FS300R12KE3BOSA1	AG-ECONOPP-1-1	FS300R12KE3BOSA1
FS450R12KE3	SP000014915	FS450R12KE3BOSA1	AG-ECONOPP-1-1	FS450R12KE3BOSA1